

# SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

# FTS2057-

# N-Channel Silicon MOSFET General-Purpose Switching Device Applications

## Features

- ON-resistance  $R_{DS}(on)1=96m\Omega(typ.)$
- Input capacitance Ciss=1030pF(typ.)
- 4V drive
- · Protection diode in
- Halogen free compliance

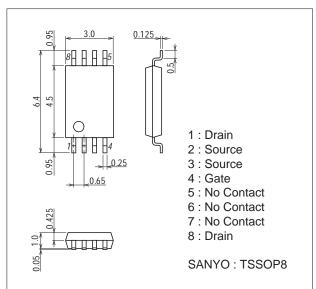
# **Specifications**

#### Absolute Maximum Ratings at Ta= $25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		3	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	12	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (2000mm <sup>2</sup> ×0.8mm)	1.3	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Package Dimensions

unit : mm (typ) 7006A-009



#### **Product & Package Information**

- Package
- JEITA, JEDEC :-
- Minimum Packing Quantity : 3,000 pcs./reel

: TSSOP8

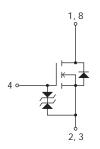
Marking

#### Packing Type : TL





#### **Electrical Connection**

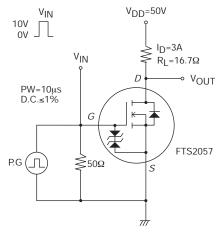


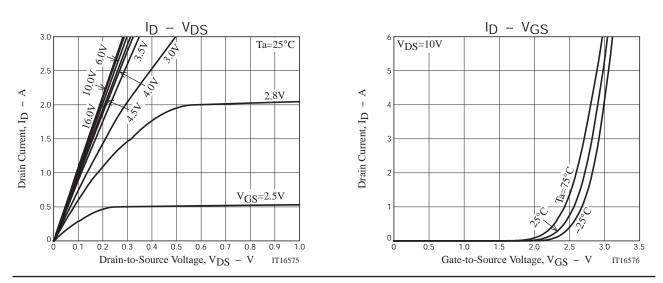
#### SANYO Semiconductor Co., Ltd. http://semicon.sanyo.com/en/network

## Electrical Characteristics at Ta=25°C

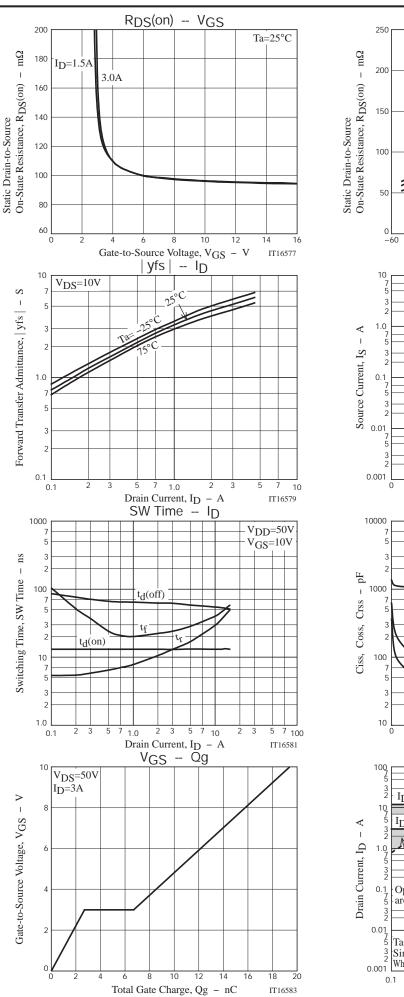
Deservation	Symbol	Conditions	Ratings			1.1
Parameter			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	100			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0V			±10	μΑ
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =3A		5.2		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	ID=3A, VGS=10V		96	125	mΩ
	R <sub>DS</sub> (on)2	ID=1.5A, VGS=4.5V		105	150	mΩ
	R <sub>DS</sub> (on)3	I <sub>D</sub> =1.5A, V <sub>GS</sub> =4V		110	155	mΩ
Input Capacitance	Ciss			1030		рF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		80		рF
Reverse Transfer Capacitance	Crss			42		рF
Turn-ON Delay Time	t <sub>d</sub> (on)			13		ns
Rise Time	tr			13		ns
Turn-OFF Delay Time	td(off)	<ul> <li>See specified Test Circuit.</li> </ul>		62		ns
Fall Time	tf			24		ns
Total Gate Charge	Qg			19.4		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =3A		2.7		nC
Gate-to-Drain "Miller" Charge	Qgd			4.0		nC
Diode Forward Voltage	V <sub>SD</sub>	IS=3A, VGS=0V	1	0.81	1.2	V

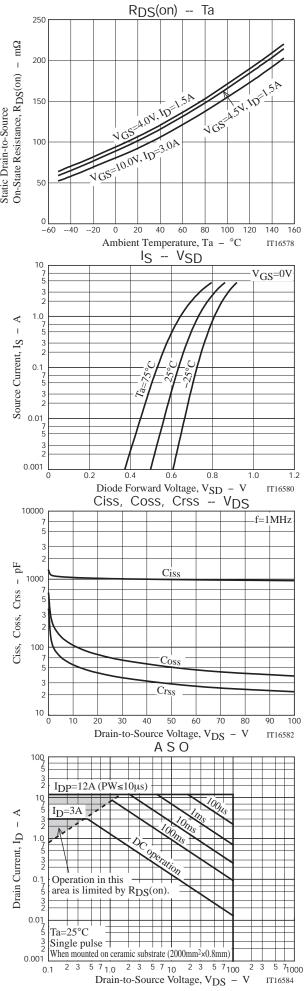
### Switching Time Test Circuit

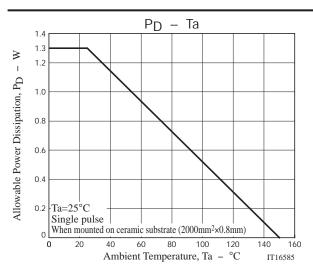




FTS2057







Note on usage : Since the FTS2057 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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